FIG.1: Maximum power dissipation versus RMS on-state current

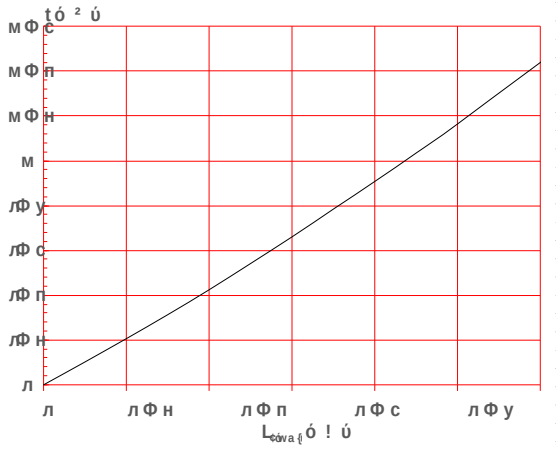
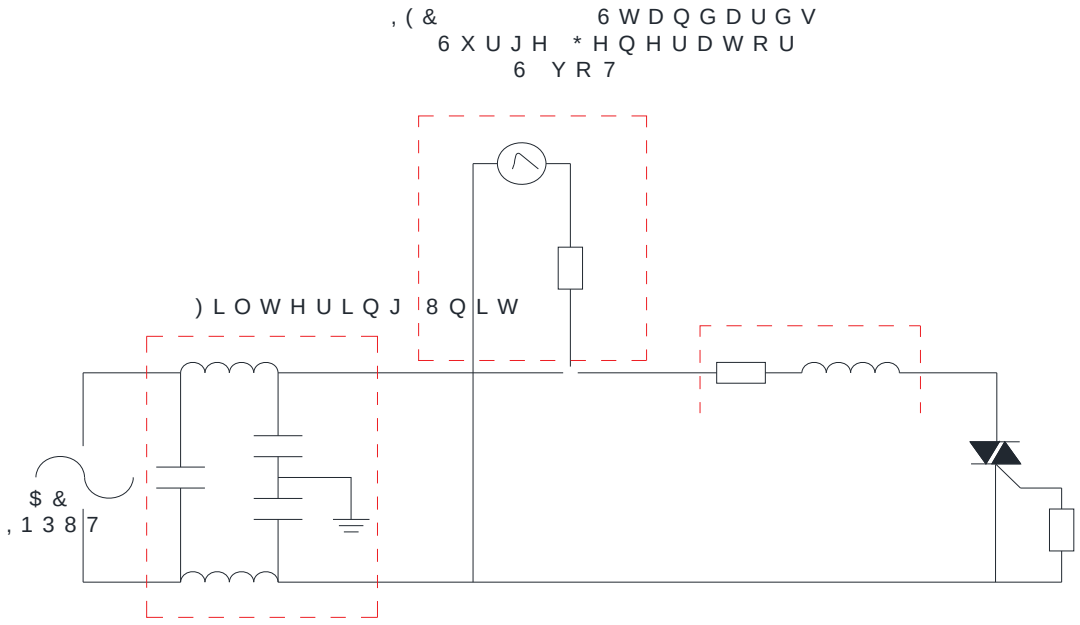


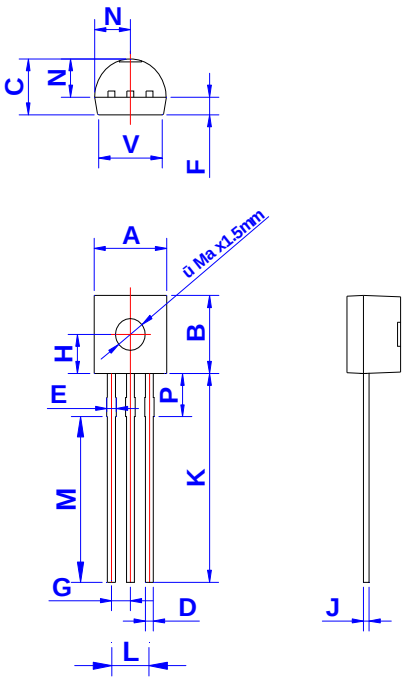
FIG.2: RMS on-state current versus case temperature



FIG. 7 Ö 7HVW FLUFXLW IRU LQGXFWLYH DQG VWDWLF ORDGV



t ! / Y ! D9 a9/I ! bL/ ! [5 ! ¢ !



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45		5.20	0.175		0.205
B	4.32		5.33	0.170		0.210
C	3.18		4.19	0.125		0.165
D	0.407		0.533	0.016		0.021
E	0.50		0.70	0.020		0.028
F	1.10		1.30	0.043		0.051
G	1.10		1.40	0.043		0.055
H	2.20		2.40	0.087		0.094
J	0.36		0.50	0.014		0.020
K	12.70		15.0	0.500		0.591
L	2.44		2.64	0.096		0.104
M	11.64		12.04	0.458		
N	2.04		2.66	0.080		0.105
P	1.80		2.30	0.071		0.091
V	4.10		4.50	0.161		0.177

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